

## Vishay Semiconductors

# **Small Signal Schottky Diode**

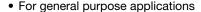


#### **MECHANICAL DATA**

Case: MiniMELF SOD-80
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

#### **FEATURES**





 The LL101 series is a metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring



 The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications

- · Integrated protection ring against static discharge
- Low capacitance
- Low leakage current
- This diode is also available in the DO-35 case with type designation SD101A, B, C and in the SOD-123 case with type designation SD101AW-V, SD101BW-V, SD101CW-V
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### **APPLICATIONS**

- HF-detector
- Protection circuit
- Diode for low currents wits a low supply voltage
- · Small battery charger
- Power supplies
- DC/DC converter for notebooks

PARTS TABLE					
PART	TYPE DIFFERENTATION	ORDERING CODE	INTERNAL CONSTRUCTION	REMARKS	
LL101A	$V_R = 60 \text{ V}, V_F \text{ at } I_F = 1 \text{ mA max. } 410 \text{ mV}$	LL101A-GS18 or LL101A-GS08	Single diode	Tape and reel	
LL101B	$V_R = 50 \text{ V}, V_F \text{ at } I_F = 1 \text{ mA max. } 400 \text{ mV}$	LL101B-GS18 or LL101B-GS08	Single diode	Tape and reel	
LL101C	$V_R = 40 \text{ V}$ , $V_F$ at $I_F = 1 \text{ mA max}$ . 390 mV	LL101C-GS18 or LL101C-GS08	Single diode	Tape and reel	

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
		LL101A	$V_{RRM}$	60	V	
Reverse voltage		LL101B	$V_{RRM}$	50	V	
		LL101C	$V_{RRM}$	40	V	
Power dissipation (infinite heatsink) (1)			P <sub>tot</sub>	400	mW	
Forward continuous courrent			I <sub>F</sub>	30	mA	
Maximum single cycle surge 10 µs square wave			I <sub>FSM</sub>	2	Α	

## Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature



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THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Junction temperature		Tj	125	°C	
Storage temperature range		T <sub>stg</sub>	- 65 to + 150	°C	
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R <sub>thJA</sub>	320	K/W	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse Breakdown Voltage	I <sub>R</sub> = 10 μA	LL101A	V <sub>(BR)</sub>	60			V
		LL101B	V <sub>(BR)</sub>	50			V
		LL101C	V <sub>(BR)</sub>	40			V
Leakage current	V <sub>R</sub> = 50 V	LL101A	I <sub>R</sub>			200	nA
	V <sub>R</sub> = 40 V	LL101B	I <sub>R</sub>			200	nA
	V <sub>R</sub> = 30 V	LL101C	I <sub>R</sub>			200	nA
Forward voltage drop	I <sub>F</sub> = 1 mA	LL101A	V <sub>F</sub>			0.410	V
	I <sub>F</sub> = 1 mA	LL101B	V <sub>F</sub>			0.400	V
	I <sub>F</sub> = 1 mA	LL101C	V <sub>F</sub>			0.390	V
	I <sub>F</sub> = 15 mA	LL101A	V <sub>F</sub>			1000	mV
		LL101B	V <sub>F</sub>			950	mV
		LL101C	V <sub>F</sub>			900	mV
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz	LL101A	C <sub>D</sub>			2.0	pF
	V <sub>R</sub> = 0 V, f = 1 MHz	LL101B	C <sub>D</sub>			2.1	pF
		LL101C	C <sub>D</sub>			2.2	pF
Reverse recovery time	$I_F = I_R = 5$ mA, recover to 0.1 $I_R$		t <sub>rr</sub>			1	ns

## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

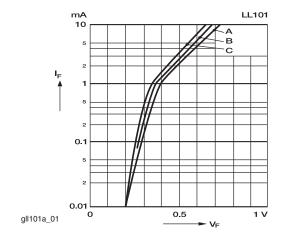


Fig. 1 - Typ. I<sub>F</sub> vs. V<sub>F</sub> for Primary Conduction through the Schottky Barrier

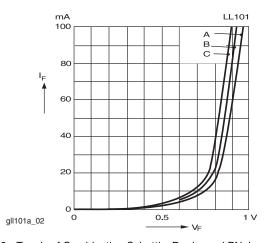


Fig. 2 - Typ.  $I_{\text{F}}$  of Combination Schottky Barrier and PN Junction Guard Ring

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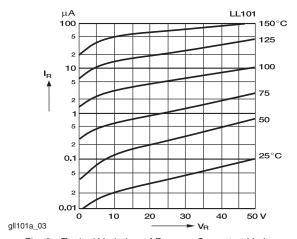


Fig. 3 - Typical Variation of Reverse Current at Various Temperatures

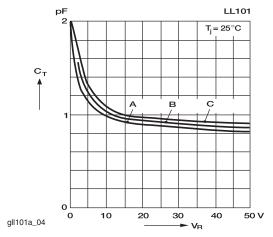
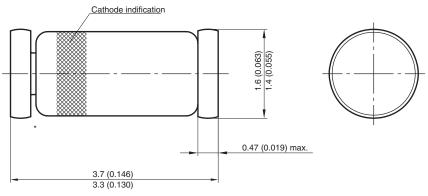


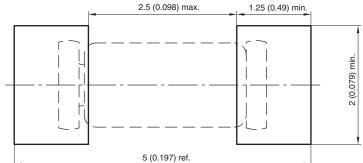
Fig. 4 - Typical Capacitance Curve as a Function of Reverse Voltage

## PACKAGE DIMENSIONS in millimeters (inches): MiniMELF SOD-80



<sup>\*</sup> The gap between plug and glass can be either on cathode or anode side

### Foot print recommendation:



Document no.:6.560-5005.01-4 Rev. 8 - Date: 07.June.2006 96 12070



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Revision: 13-Jun-16 1 Document Number: 91000